# QOUND

### QPA9940 2300-2400MHz 4 W High-Efficiency Amplifier

#### **Product Overview**

The QPA9940 is a high-efficiency, linearizable power amplifier targeting Band 40 small-cell wireless infrastructure systems. Using InGaP/GaAs HBT technology, the product delivers high efficiency of 31% at +28dBm average output power while providing excellent DPD linearized ACPR of -50 dBc for signal bandwidths of up to 100MHz.

The QPA9940 is housed in a 5x5mm SMT package. It is pin-to-pin compatible to QPA9901, QPA9903 and QPA9908 (high-efficiency small cell PA).



16 Pad 5 x 5 mm Package

#### **Key Features**

- 2300-2400 MHz
- 34.5 dB Gain
- Over 36 dBm P3dB
- 31% PAE at +28 dBm power output
- -50 dBc ACPR DPD Linearized at +28 dBm Power Output with 5-carrier signal
- 1.8V Logic Compatible PA ON/OFF Control
- On Chip ESD Protection
- 5 x 5 mm Package

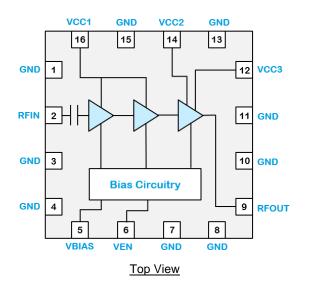
#### **Applications**

- 4G/5G Small-cell BTS
- 5G M-MIMO
- Repeaters / DAS
- Mobile Infrastructure
- General Purpose Wireless

#### **Ordering Information**

Part No.	Description
QPA9940TR13	2500pcs on 13" reel
QPA9940EVB-01	2300-2400 MHz EVB

#### Functional Block Diagram





#### QPA9940 2300-2400MHz 4 W High-Efficiency Amplifier

#### **Absolute Maximum Ratings**

Parameter	Rating
Storage Temperature	-55 to +125 °C
RF Input Power, Pulsed CW, 50 $\Omega^{(1)}$	+10 dBm
Device Voltage (Vcc)	+5.5 V

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability.

1. 2300-2400 MHz, Pulsed CW, 10% duty cycle, 100us period

#### **Recommended Operating Conditions**

Parameter	Min	Тур	Max	Units
Device Voltage (Vcc)	+4.75	+5	+5.25	V
TCASE	-40		+105	°C
Tj for >10 <sup>6</sup> hours MTTF			+175	°C

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

#### **Electrical Specifications**

Parameter	Conditions <sup>(1)</sup>	Min	Тур	Max	Units
Operational Frequency Range		2300		2400	MHz
Test Frequency			2350		MHz
Gain <sup>(2)</sup>	At +28dBm Pout and room temperature	32	34.5		dB
Input Return Loss			-17		dB
Output Return Loss			-15		dB
Output P3dB	10 µs pulse width, 10% duty cycle	35.1	+36		dBm
Power Added Efficiency (2)	Pout = +28 dBm	28.1	31		%
ACPR (Uncorrected) <sup>(2)</sup>	Pout = +28 dBm		-31	-28.4	dBc
ACPR (Uncorrected) <sup>(3)</sup>	Pout = +28 dBm		-29		dBc
ACPR (Corrected) <sup>(3)</sup>	Pout = +28 dBm		-50		dBc
Quiescent Current, Icq	Pins 12, 14 and 16		100		mA
Total Operating Current	Pin 5, 12, 14 and 16, Pout = +28 dBm		406		mA
Thermal Resistance, $\theta_{jc}$	Junction to case		23.3		°C/W
V <sub>EN</sub> High		1.17	1.8	Vcc	V
V <sub>EN</sub> Low		0	0	0.63	V
2nd Harmonic	Pout = +28 dBm		-40		dBc
3rd Harmonic	Pout = +28 dBm		-54		dBc
Turn-on time	Measured from 50% PA enable voltage level to 90% of RF amplitude		0.5		us

Notes:

1. Test conditions unless otherwise noted: All V<sub>CC</sub> & V<sub>BIAS</sub> = +5.0 V, V<sub>EN</sub> = +1.8 V, Temp = +25 °C, 50  $\Omega$  system.

2. LTE, 20 MHz E-UTRA Test Mode 1.1 or 3.1, PAR = 8.5 dB at 0.01% probability.

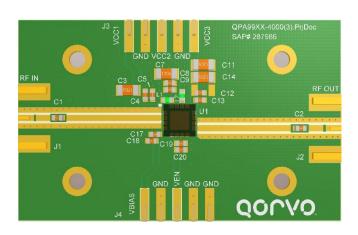
3. LTE, 20 MHz x 5 E-UTRA Test Mode 1.1 or 3.1, PAR = 8.5 dB at 0.01% probability.

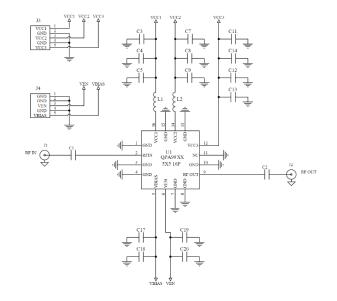
#### Power Amplifier Enable Logic Table

Parameter	High	Low
VEN	Power Amplifier ON	Power Amplifier OFF

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#### **QPA9940 EVB Layout and Schematic**





#### Notes:

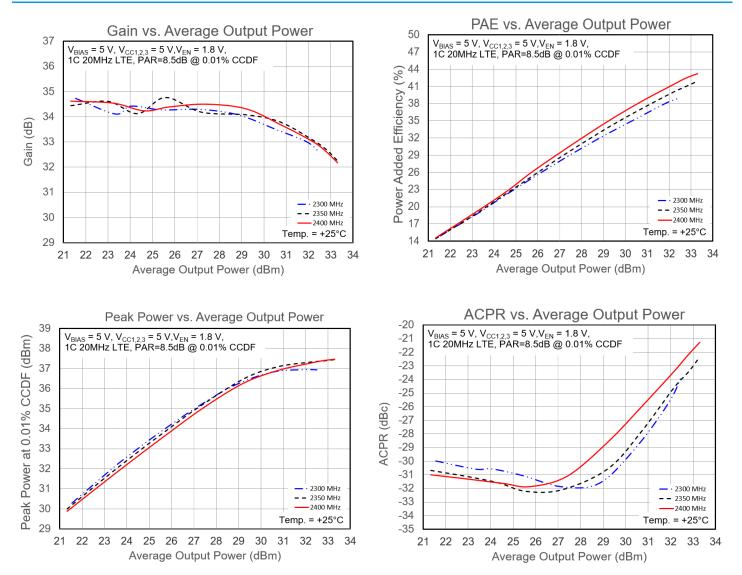
1. See Evaluation Board PCB Information for material and stack up.

#### Bill of Materials – QPA9940EVB-01

Reference Des.	Value	Description	Manuf.	Part Number
U1	-	Amplifier, QPA9940 2300-2400MHz, High-Efficiency	Qorvo	QPA9940
C1, C2	100 pF	CAP,100 pF, 0603, 5%, 50V, C0G	various	
C5, C9, C13, C17, C19	1000 pF	CAP,1000 pF, 0603, 5%, 50V, C0G	various	
C4, C8, C12, C18, C20	0.1 µF	CAP,0.1 µF, 0603, 10%, 50V, X7R	various	
C3, C7, C14	10 µF	CAP, 10 μF, 1206, 25V	various	
L1, L2	0 Ω	RES 0 Ω, 0603, 1/16W, Chip	various	
J1, J2	-	CONN. RF. SMA. F. STRT. Edge Mount	various	
J3, J4	-	Connector, 5 Pin	various	

#### QPA9940 2300-2400MHz 4 W High-Efficiency Amplifier

#### **Performance Plots - LTE**

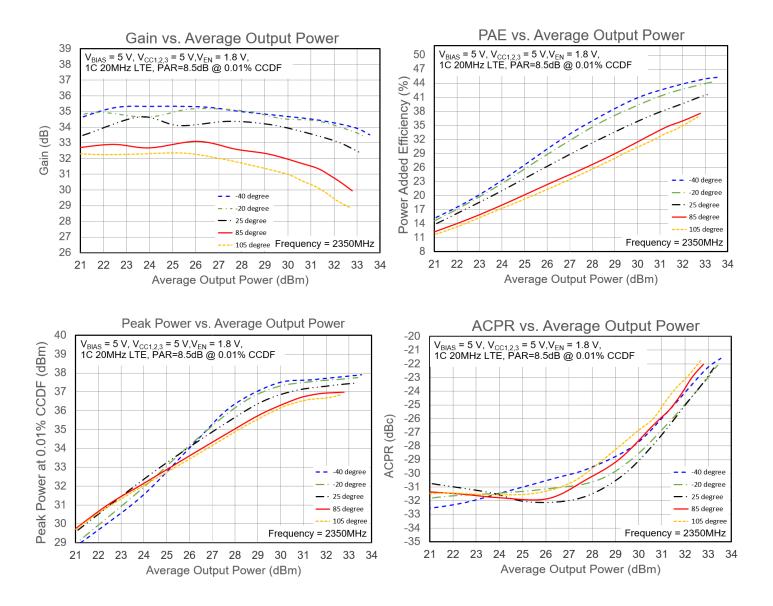


Test conditions unless otherwise noted:  $V_{BIAS} = 5 V$ ,  $V_{CC1,2,3} = 5 V$ ,  $V_{EN} = 1.8 V$ ,  $T = +25^{\circ}C$ , tested using a single-carrier, 20 MHz LTE signal with 8.5 dB PAR at 0.01% CCDF on a reference design fixture.

# QOrvo

#### QPA9940 2300-2400MHz 4 W High-Efficiency Amplifier

#### **Performance Plots - LTE**

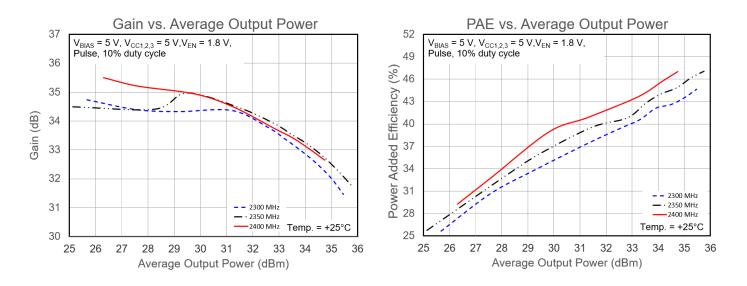


Test conditions unless otherwise noted: V<sub>BIAS</sub> = 5 V, V<sub>CC1,2,3</sub> = 5 V, V<sub>EN</sub> = 1.8 V, tested at 2350 MHz using a single-carrier, 20 MHz LTE signal with 8.5 dB PAR at 0.01% CCDF on a reference design fixture.

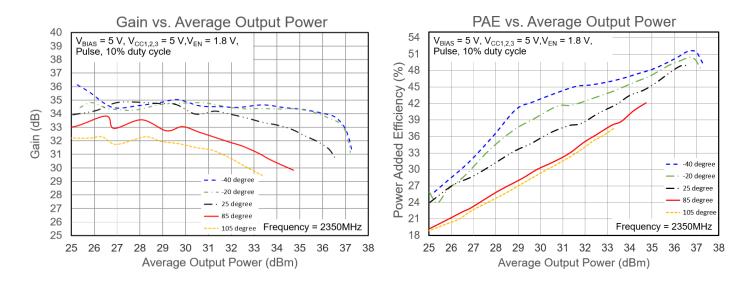
# QOrvo

#### QPA9940 2300-2400MHz 4 W High-Efficiency Amplifier

#### **Performance Plots - Pulse**



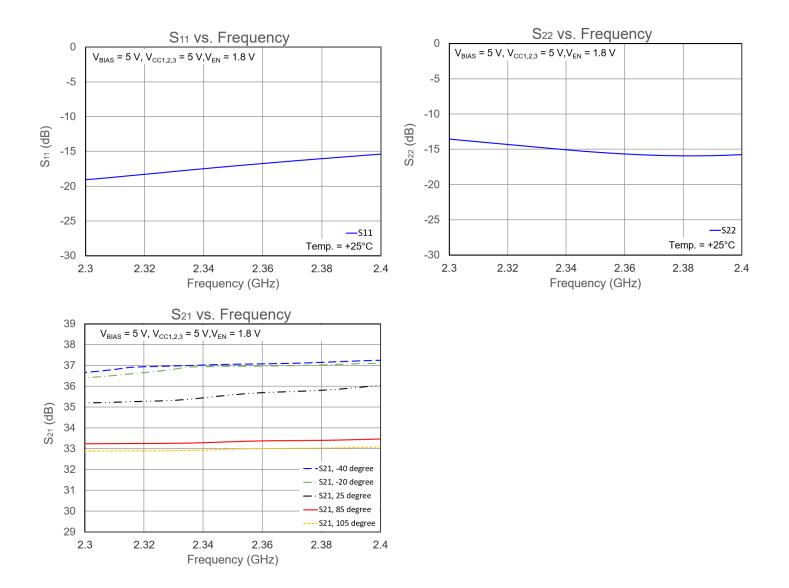
Test conditions unless otherwise noted:  $V_{BIAS} = 5 V$ ,  $V_{CC1,2,3} = 5 V$ ,  $V_{EN} = 1.8 V$ ,  $T = +25^{\circ}C$ , tested using a pulse signal, 10% duty cycle.



Test conditions unless otherwise noted:  $V_{BIAS} = 5 V$ ,  $V_{CC1,2,3} = 5 V$ ,  $V_{EN} = 1.8 V$ , tested at 2350 MHz using a pulse signal, 10% duty cycle.

#### QPA9940 2300-2400MHz 4 W High-Efficiency Amplifier

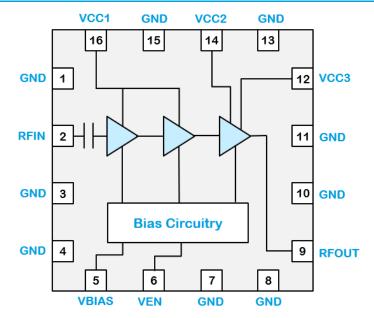
#### **Performance Plots – S-parameters**



Test conditions unless otherwise noted:  $V_{BIAS} = 5 V$ ,  $V_{CC1,2,3} = 5 V$ ,  $V_{EN} = 1.8 V$ .

#### QPA9940 2300-2400MHz 4 W High-Efficiency Amplifier

#### **Pad Configuration and Description**



Top View

Pad No.	Label	Description
1, 3, 4, 7, 8,10, 11, 13, 15	GND	Ground connection.
2	RF <sub>IN</sub>	RF input, internally matched to $50\Omega$ and DC blocked.
5	VBIAS	Bias circuit supply voltage
6	V <sub>EN</sub>	Amplifier enable voltage (regulated internally)
9	RFout	RF output, internally matched to $50\Omega$ and DC shorted. External DC blocking capacitor required
12	V <sub>CC3</sub>	Supply voltage for the various amplifier stages
14	V <sub>CC2</sub>	Supply voltage for the various amplifier stages
16	V <sub>CC1</sub>	Driver stage supply voltage
Backside Paddle	GND	Ground connection. The back side of the package should be connected to the ground plane through as short of a connection as possible. PCB via holes under the device are recommended.



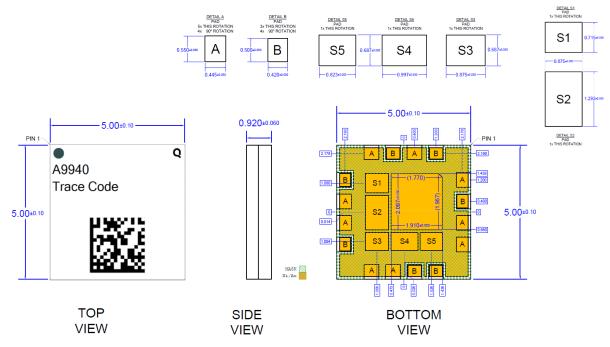
### QPA9940 2300-2400MHz 4 W High-Efficiency Amplifier

#### **Package Marking and Dimensions**

Marking: Pin 1 Indicator and Qorvo Logo

Part Number – QPA9940

Trace Code – XXXXXX Up to 8 Characters to be Assigned by sub-Contractor



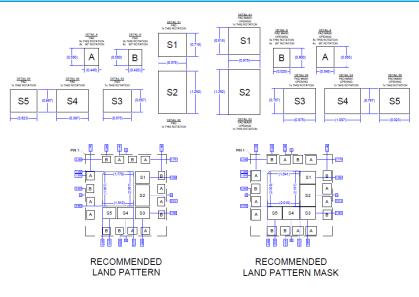
Notes:

1. All dimensions are in millimeters. Angles are in degrees.

2. The terminal #1 identifier and terminal numbering conform to JESD 95-1 SPP-012.

3. Contact plating: ENEPIG

#### **PCB Mounting Pattern**



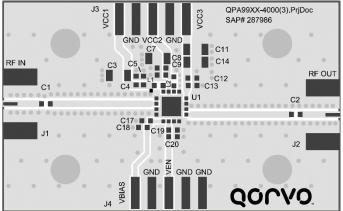
### QOUNO.

#### **QPA9940** 2300-2400MHz 4 W High-Efficiency Amplifier

#### **Evaluation Board PCB Information**

#### **PC Board Layout**

Layer	Name	Material	Thickness	Constant
1	Top Overlay			
2	Top Solder	Solder Resist	0.40 mil	3.5
3	Top Layer	Copper	1.40 mil	
4	Dielectric1	RO4350	20.00 mil	3.48
5	Bottom Layer	Copper	1.40 mil	



Total thickness: 23.2mill

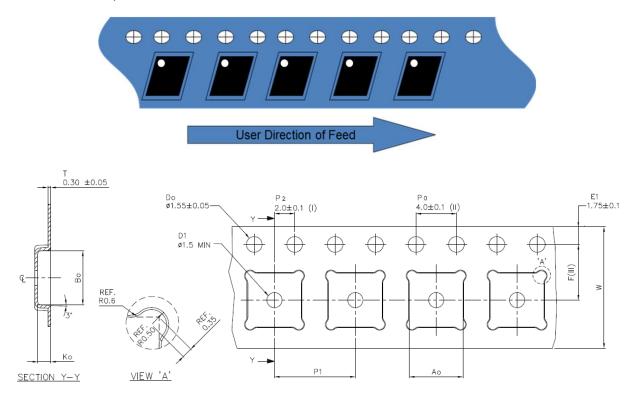
#### Notes:

- 1. All dimensions are in millimeters. Angles are in degrees.
- 2. Use 1 oz. copper minimum for top and bottom layer metal.
- 3. Via holes are required under the backside paddle of this device for proper RF/DC grounding and thermal dissipation. We recommend a 0.35mm (#80/.0135") diameter bit for drilling via holes and a final plated thru diameter of 0.25 mm (0.10").
- 4. Ensure good package backside paddle solder attach for reliable operation and best electrical performance.

#### QPA9940 2300-2400MHz 4 W High-Efficiency Amplifier

#### Tape and Reel Information – Carrier and Cover Tape Dimensions

Tape and reel specifications for this part are also available on the Qorvo website. Standard T/R size = 2500 pieces on a 13" reel.



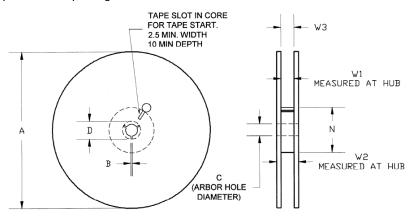
Feature	Measure	Symbol	Size (in)	Size (mm)
	Length	A0	0.209	5.3
Cavity	Width	B0	0.209	5.3
Cavity	Depth	K0	0.051	1.3
	Pitch	P1	0.315	8.0
	Cavity to Perforation - Length Direction	P2	0.079	2.0
Centerline Distance	Cavity to Perforation - Width Direction	F	0.217	5.5
Cover Tape	Width	С	0.362	9.2
Carrier Tape	Width	W	0.472	12

### QONOD

#### QPA9940 2300-2400MHz 4 W High-Efficiency Amplifier

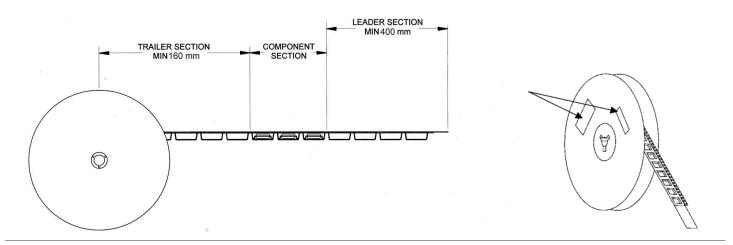
#### **Tape and Reel Information – Reel Dimensions**

Packaging reels are used to prevent damage to devices during shipping and storage, loaded carrier tape is typically wound onto a plastic take-up reel. The reel size is 13" diameter. The reels are made from high-impact injection-molded polystyrene (HIPS), which offers mechanical and ESD protection to packaged devices.



Feature	Measure	Symbol	Size (in)	Size (mm)
	Diameter	A	12.992	330.00
Flange	Thickness	W2	0.717	18.20
	Space Between Flange	W1	0.504	12.80
Hub	Outer Diameter	N	4.016	102.00
	Arbor Hole Diameter	С	0.512	13.00
	Key Slit Width	В	0.079	2.00
	Key Slit Diameter	D	0.795	20.2

#### **Tape and Reel Information – Tape Length and Label Placement**



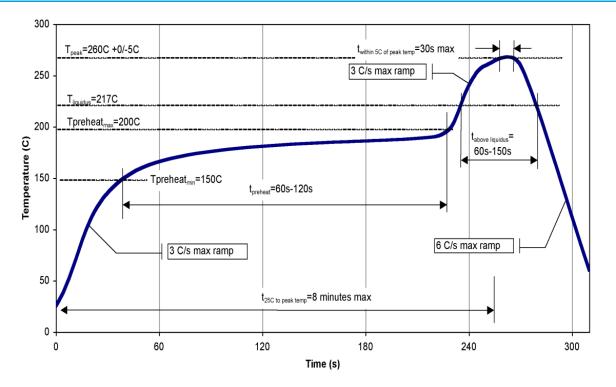
#### Notes:

1. Empty part cavities at the trailing and leading ends are sealed with cover tape. See EIA 481-1-A.

2. Labels are placed on the flange opposite the sprockets in the carrier tape.

#### QPA9940 2300-2400MHz 4 W High-Efficiency Amplifier

### **Recommended Solder Temperature Profile**





#### Handling Precautions

Parameter	Rating	Standard	
ESD–Human Body Model (HBM)	Class 1C	ESDA/JEDEC JS-001-2012	Caution!
ESD-Charged Device Model (CDM)	Class C3	JEDEC JESD22-C101F	ESD-Sensitive Device
MSL-Moisture Sensitivity Level	Level 3	IPC/JEDEC J-STD-020	

#### Solderability

Compatible with both lead-free (260°C max. reflow temp.) and tin/lead (245°C max. reflow temp.) soldering processes. Solder profiles available upon request.

Contact plating: ENEPIG

#### **RoHS Compliance**

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU. This product also has the following attributes:

- Product uses RoHS Exemption 7c-I to meet RoHS Compliance requirements.
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C15H12Br402) Free
- PFOS Free
- SVHC Free

#### **Contact Information**

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: <u>www.qorvo.com</u>

Tel: 1-844-890-8163

Email: <u>customer.support@qorvo.com</u>

For technical questions and application information:

Email: appsupport@gorvo.com

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